

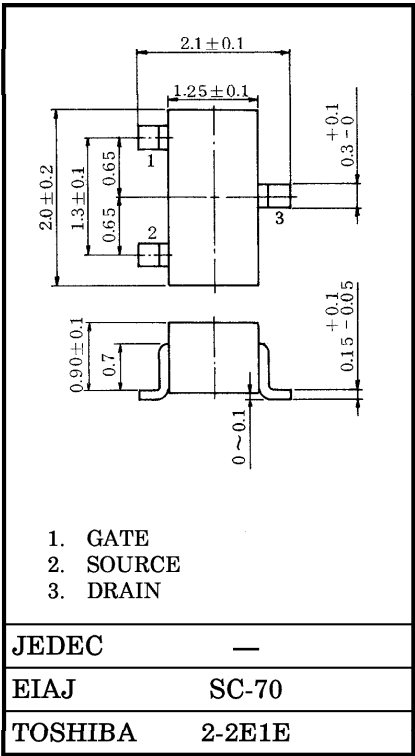
2SK2034

HIGH SPEED SWITCHING APPLICATIONS.
ANALOG SWITCH APPLICATIONS.

- High Input Impedance.
- Low Gate Threshold Voltage : $V_{th}=0.5\sim1.5V$
- Excellent Switching Times : $t_{on}=0.16\mu s$ (typ.)
 $t_{off}=0.15\mu s$ (typ.)
- Small Package.
- Enhancement-Mode

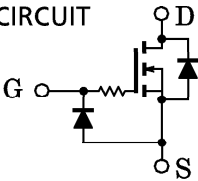
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GSS}	10	V
DC Drain Current	I_D	100	mA
Drain Power Dissipation	P_D	100	mW
Channel Temperature	T_{ch}	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C

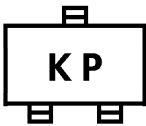


Weight : 0.006g

EQUIVALENT CIRCUIT



MARKING



THIS TRANSISTOR ELECTROSTATIC SENSITIVE DEVICE. PLEASE HANDLE WITH CAUSHON.

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage Current		IGSS	VGS=10V, VDS=0	—	—	1	μA
Drain-Source Breakdown Voltage		V(BR)DSS	ID=100μA, VGS=0	20	—	—	V
Drain Cut-off Current		IDSS	VDS=20V, VGS=0	—	—	1	μA
Gate Threshold Voltage		Vth	VDS=3V, ID=0.1mA	0.5	—	1.5	V
Forward Transfer Admittance		Yfs	VDS=3V, ID=10mA	25	50	—	mS
Drain-Source ON Resistance		RDS(ON)	ID=10mA, VGS=2.5V	—	8	12	Ω
Input Capacitance		Ciss	VDS=3V, VGS=0, f=1MHz	—	8.5	—	pF
Reverse Transfer Capacitance		Crss	VDS=3V, VGS=0, f=1MHz	—	3.3	—	pF
Output Capacitance		Coss	VDS=3V, VGS=0, f=1MHz	—	9.3	—	pF
Switching Time	Turn-on Time	ton	VDD=3V, ID=10mA VGS=0~2.5V	—	0.16	—	μs
	Turn-off Time	toff	VDD=3V, ID=10mA VGS=0~2.5V	—	0.15	—	μs

SWITCHING TIME TEST CIRCUIT

